## NSN 5961-00-881-3416

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-881-3416 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Height:** 0.437 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug **Specification Data:** 80131-release3376 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** 

No

Demilitarization:

## **NSN 5961-00-881-3416** Transistor - Page 2 of 2



Fiig:

A110a0